## NSN 5962-01-330-5549

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View Online at https://aerobasegroup.com/nsn/5962-01-330-5549 **Body Length:** 1.280 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** Between 0.140 inches and 0.185 inches **Maximum Power Dissipation Rating:** 1.2 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** Radar set an/tps-63 (v) **Features Provided:** Monolithic and hermetically sealed and programmed and burn in and ultraviolet erasable **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 22 input **Case Outline Source And Designator:** D-9 mil-m-38510 **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 7.0 volts total supply **Time Rating Per Chacteristic:** 25.00 nanoseconds propagation delay time, low to high level output and 25.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Pal **Terminal Type And Quantity:** 24 printed circuit Shelf Life: N/a

Demilitarization:

**Unit Of Measure:** 

Yes - demil/mli

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